

SNOS436H-AUGUST 2000-REVISED APRIL 2013

LMV921/LMV922/LMV924 Single, Dual and Quad 1.8V, 1MHz, Low Power Operational Amplifiers with Rail-To-Rail Input and Output

Check for Samples: LMV921, LMV922, LMV924

FEATURES

- (Typical 1.8V Supply Values; Unless Otherwise Noted)
- Ensured 1.8V, 2.7V and 5V Specifications
- Rail-to-Rail Input & Output Swing
- w/600Ω Load 100 mV from Rail
- w/2kΩ Load 30 mV from Rail
- V_{CM} 300mV Beyond Rails
- Supply Current 145µA/amplifier
- Gain Bandwidth Product 1MHz
- LMV921 Maximum V_{os} 6mV
- 90dB Gain w/600Ω Load
- LMV921 Available in Ultra Tiny, SC70-5 Package
- LMV922 Available in VSSOP-8 Package
- LMV924 Available in TSSOP-14 Package

APPLICATIONS

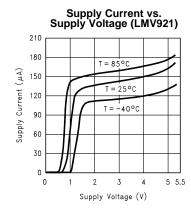
- Cordless/Cellular Phones
- Laptops
- PDAs
- PCMCIA
- Portable/Battery-Powered Electronic Equipment
- Supply Current Monitoring
- Battery Monitoring

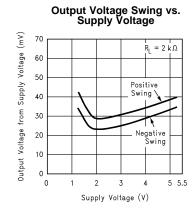
DESCRIPTION

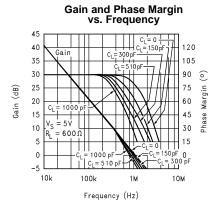
The LMV921 Single/LMV922 Dual/LMV924 Quad are ensured to operate from +1.8V to +5.0V supply voltages and have rail-to-rail input and output. This rail-to-rail operation enables the user to make full use of the entire supply voltage range. The input common mode voltage range extends 300mV beyond the supplies and the output can swing rail-to-rail unloaded and within 100mV from the rail with 600 Ω load at 1.8V supply. The LMV921/LMV922/LMV924 are optimized to work at 1.8V which make them ideal for portable two-cell battery-powered systems and single cell Li-lon systems.

The LMV921/LMV922/LMV924 exhibit excellent speed-power ratio, achieving 1MHz gain bandwidth product at 1.8V supply voltage with very low supply current. The LMV921/LMV922/LMV924 are capable of driving 600Ω load and up to 1000pF capacitive load with minimal ringing. The LMV921/LMV922/LMV924's high DC gain of 100dB makes them suitable for low frequency applications.

The LMV921 (Single) is offered in a space saving SC70–5 and SOT-23–5 packages. The SC70–5 package is only 2.0X2.1X1.0mm. These small packages are ideal solutions for area constrained PC boards and portable electronics such as cellphones and PDAs.







Texa

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS(1)(2)

ESD Tolerance ⁽³⁾	Machine Model	100V	
	Human Body Model	2000V	
Differential Input Voltage		± Supply Voltage	
Supply Voltage (V ⁺ –V ⁻)		5.5V	
Output Short Circuit to V ⁺⁽⁴⁾			
Output Short Circuit to V ⁻⁽⁴⁾			
Storage Temperature Range		−65°C to 150°C	
Junction Temperature ⁽⁵⁾		150°C	
Mounting Temp.	Infrared or Convection (20 sec)	235°C	

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
- (3) Human body model, 1.5 k Ω in series with 100pF. Machine model, 200 Ω in series with 100 pF.
- (4) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45mA over long term may adversely affect reliability.
- (5) The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

OPERATING RATINGS(1)

Supply Voltage	Supply Voltage		
Temperature Range			-40°C ≤ T _J ≤ 85°C
Thermal Resistance (θ _{JA})	Ultra Tiny SC70-5 Package	5-Pin Surface Mount	440 °C/W
	Tiny SOT-23-5 Package	5-Pin Surface Mount	265 °C/W
	VSSOP Package	8-Pin Surface Mount	235°C/W
	TSSOP Package	14-Pin Surface Mount	155°C/W
	SOIC Package	8-Pin Surface Mount	175°C/W
		14-Pin Surface Mount	127°C/W

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.

Product Folder Links: LMV921 LMV922 LMV924

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1.8V DC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits specified for $T_J = 25^{\circ}C$. $V^+ = 1.8V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ ⁽¹⁾	Limits ⁽²⁾	Units
V _{OS}	Input Offset Voltage	LMV921 (Single)	-1.8	6 8	mV max
		LMV922 (Dual) LMV924 (Quad)	-1.8	8 9.5	mV max
TCV _{OS}	Input Offset Voltage Average Drift		1		μV/°C
I _B	Input Bias Current		12	35 50	nA max
I _{OS}	Input Offset Current		2	25 40	nA max
Is	Supply Current	LMV921 (Single)	145	185 205	
		LMV922 (Dual)	330	400 550	μA max
		LMV924 (Quad)	560	700 850	
CMRR	Common Mode Rejection Ratio	$0 \le V_{CM} \le 0.6V$	82	62 60	dB
		$-0.2V \le V_{CM} \le 0V$ 1.8V $\le V_{CM} \le 2.0V$	74	50	min
PSRR	Power Supply Rejection Ratio	$1.8V \le V^+ \le 5V$, $V_{CM} = 0.5V$	78	67 62	dB min
V _{CM}	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	-0.3	-0.2 0	V min
			2.15	2.0 1.8	V max
A _V	Large Signal Voltage Gain LMV921 (Single) Large Signal Voltage Gain LMV922 (Dual) LMV924 (Quad)	$R_L = 600\Omega$ to 0.9V, $V_O = 0.2V$ to 1.6V, $V_{CM} = 0.5V$	91	77 73	dB min dB min
		$R_L = 2k\Omega$ to 0.9V, $V_O = 0.2V$ to 1.6V, $V_{CM} = 0.5V$	95	80 75	
		$R_L = 600\Omega$ to 0.9V, $V_O = 0.2V$ to 1.6V, $V_{CM} = 0.5V$	79	65 61	
		$R_L = 2k\Omega$ to 0.9V, $V_O = 0.2V$ to 1.6V, $V_{CM} = 0.5V$	83	68 63	
V _O	Output Swing	$R_L = 600\Omega$ to 0.9V $V_{IN} = \pm 100$ mV	1.7	1.65 1.63	V min
			0.075	0.090 0.105	V max
		$R_L = 2k\Omega$ to 0.9V V _{IN} = ± 100mV	1.77	1.75 1.74	V min
			0.025	0.035 0.040	V max
I _O	Output Short Circuit Current	Sourcing, $V_0 = 0V$ $V_{IN} = 100 \text{mV}$	6	4 3.3	mA min
		Sinking, $V_O = 1.8V$ $V_{IN} = -100 \text{mV}$	10	7 5	mA min

⁽¹⁾ Typical Values represent the most likely parametric norm.

²⁾ All limits are specified by testing or statistical analysis.



1.8V AC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits specified for $T_J = 25^{\circ}C$. $V^+ = 1.8V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ ⁽¹⁾	Units
SR	Slew Rate	See ⁽²⁾	0.39	V/µs
GBW	Gain-Bandwidth Product		1	MHz
Φ _m	Phase Margin		60	Deg
G _m	Gain Margin		10	dB
e _n	Input-Referred Voltage Noise	f = 1 kHz, V _{CM} = 0.5V	45	nV/√ Hz
i _n	Input-Referred Current Noise	f = 1 kHz	0.1	pA/ √ Hz
THD	Total Harmonic Distortion	$ f = 1kHz, A_V = +1 $ $R_L = 600k\Omega, V_{IN} = 1 V_{PP} $	0.089	%
	Amp-to-Amp Isolation	See ⁽³⁾	140	dB

- (1) Typical Values represent the most likely parametric norm.
- (2) V⁺ = 5V. Connected as voltage follower with 5V step input. Number specified is the slower of the positive and negative slew rates.
- (3) Input referred, $V^+ = 5V$ and $R_L = 100k\Omega$ connected to 2.5V. Each amp excited in turn with 1kHz to produce $V_0 = 3V_{PP}$.

2.7V DC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits specified for $T_J = 25^{\circ}\text{C}$. $V^+ = 2.7\text{V}$, $V^- = 0\text{V}$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ ⁽¹⁾	Limits ⁽²⁾	Units
Vos	Input Offset Voltage	LMV921 (Single)	-1.6	6 8	mV max
		LMV922 (Dual) LMV924 (Quad)	-1.6	8 9.5	mV max
TCV _{OS}	Input Offset Voltage Average Drift		1		μV/°C
I _B	Input Bias Current		12	35 50	nA max
I _{OS}	Input Offset Current		2	25 40	nA max
Is	Supply Current	LMV921 (Single)	147	190 210	
		LMV922 (Dual)	380	450 600	uA max
		LMV924 (Quad)	580	750 900	
CMRR	Common Mode Rejection Ratio	0V ≤ V _{CM} ≤ 1.5V	84	62 60	dB
		$-0.2V \le V_{CM} \le 0V$ 2.7V \le V_{CM} < 2.9V	73	50	min
PSRR	Power Supply Rejection Ratio	$1.8V \le V^+ \le 5V$, $V_{CM} = 0.5V$	78	67 62	dB min
V _{CM}	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	-0.3	-0.2 0	V min
			3.050	2.9 2.7	V max

(1) Typical Values represent the most likely parametric norm.

(2) All limits are specified by testing or statistical analysis.

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2.7V DC ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise specified, all limits specified for T_J = 25°C. V^+ = 2.7V, V^- = 0V, V_{CM} = $V^+/2$, V_O = $V^+/2$ and R_L > 1 $M\Omega$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ ⁽¹⁾	Limits ⁽²⁾	Units
A _V	Large Signal Voltage Gain LMV921 (Single)	$R_L = 600\Omega$ to 1.35V, $V_O = 0.2V$ to 2.5V	98	80 75	dB
		$R_L = 2k\Omega$ to 1.35V, $V_O = 0.2V$ to 2.5V	103	83 77	min
	Large Signal Voltage Gain LMV922 (Dual)	$R_L = 600\Omega$ to 1.35V, $V_O = 0.2V$ to 2.5V	86	68 63	dB
	LMV924 (Quad)	$R_L = 2k\Omega$ to 1.35V, $V_O = 0.2V$ to 2.5V	91	71 65	min
Vo	Output Swing	$R_L = 600\Omega$ to 1.35V $V_{IN} = \pm 100$ mV	2.62	2.550 2.530	V min
			0.075	0.095 0.115	V max
		$R_L = 2k\Omega$ to 1.35V $V_{IN} = \pm 100$ mV	2.675	2.650 2.640	V min
			0.025	0.040 0.045	V max
I _O	Output Short Circuit Current	Sourcing, V _O = 0V V _{IN} = 100mV	27	20 15	mA min
		Sinking, $V_0 = 2.7V$ $V_{IN} = -100mV$	28	22 16	mA min

2.7V AC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits specified for $T_J = 25^{\circ}C$. $V^+ = 2.7V$, $V^- = 0V$, $V_{CM} = 1.0V$, $V_O = 1.35V$ and $R_L > 1$ M Ω . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ ⁽¹⁾	Units
SR	Slew Rate	See ⁽²⁾	0.41	V/µs
GBW	Gain-Bandwidth Product		1	MHz
Фт	Phase Margin		65	Deg.
G _m	Gain Margin		10	dB
e _n	Input-Referred Voltage Noise	f = 1 kHz, V _{CM} = 0.5V	45	nV/√ Hz
i _n	Input-Referred Current Noise	f = 1 kHz	0.1	pA/ √ Hz
THD	Total Harmonic Distortion	$f=1 \text{ kHz, } A_V=+1 \\ R_L=600 \text{k}\Omega, \ V_{\text{IN}}=1 \text{ V}_{\text{PP}}$	0.077	%
	Amp-to-Amp Isolation	See ⁽³⁾	140	dB

Typical Values represent the most likely parametric norm.

 V^+ = 5V. Connected as voltage follower with 5V step input. Number specified is the slower of the positive and negative slew rates. Input referred, V^+ = 5V and R_L = 100k Ω connected to 2.5V. Each amp excited in turn with 1kHz to produce V_O = 3V_{PP}.



5V DC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits specified for $T_J = 25^{\circ}C$. $V^+ = 5V$, $V^- = 0V$, $V_{CM} = V^+/2$, $V_O = V^+/2$ and $R_L > 1$ M Ω .**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Typ ⁽¹⁾	Limits ⁽²⁾	Units
V _{OS}	Input Offset Voltage	LMV921 (Single)	-1.5	6 8	mV max
		LMV922 (Dual) LMV924 (Quad)	−1.5	8 9.5	mV max
TCV _{OS}	Input Offset Voltage Average Drift		1		μV/°C
I _B	Input Bias Current		12	35 50	nA max
I _{OS}	Input Offset Current		2	25 40	nA max
Is	Supply Current	LMV921 (Single)	160	210 230	
		LMV922 (Dual)	400	500 700	μA max
		LMV924 (Quad)	750	850 980	
CMRR	Common Mode Rejection Ratio	0V ≤ V _{CM} ≤ 3.8V	86	62 61	dB
		-0.2V ≤ V _{CM} ≤ 0V 5.0V ≤ V _{CM} ≤ 5.2V	72	50	min
PSRR	Power Supply Rejection Ratio	$1.8V \le V^+ \le 5V$ $V_{CM} = 0.5V$	78	67 62	dB min
V _{CM}	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	-0.3	-0.2 0	V min
			5.350	5.2 5.0	V max
A _V	Voltage Gain LMV921 (Single) Voltage Gain LMV922 (Dual) LMV924 (Quad)	$R_L = 600\Omega$ to 2.5V $V_O = 0.2V$ to 4.8V	104	86 82	dB
		$R_L = 2k\Omega \text{ to } 2.5V$ $V_O = 0.2V \text{ to } 4.8V$	108	89 85	min
		$R_L = 600\Omega$ to 2.5V $V_O = 0.2V$ to 4.8V	90	72 68	dB
		$R_L = 2k\Omega \text{ to } 2.5V$ $V_O = 0.2V \text{ to } 4.8V$	96	77 73	min
V _O	Output Swing	$R_L = 600\Omega \text{ to } 2.5V$ $V_{IN} = \pm 100 \text{mV}$	4.895	4.865 4.840	V min
			0.1	0.135 0.160	V max
		$R_L = 2k\Omega$ to 2.5V $V_{IN} = \pm 100$ mV	4.965	4.945 4.935	V min
			0.035	0.065 0.075	V max
I _O	Output Short Circuit Current	LMV921 Sourcing, V _O = 0V V _{IN} = 100mV	98	85 68	mA
		LMV922, LMV924 Sourcing, $V_0 = 0V$ $V_{IN} = 100 \text{mV}$	60	35	min
		Sinking, $V_0 = 5V$ $V_{IN} = -100 \text{mV}$	75	65 45	mA min

⁽¹⁾ Typical Values represent the most likely parametric norm.

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⁽²⁾ All limits are specified by testing or statistical analysis.

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5V AC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all limits specified for T_J = 25°C. V^+ = 5V, V^- = 0V, V_{CM} = $V^+/2$, V_O = 2.5V and R $_L$ > 1 M Ω . Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ ⁽¹⁾	Units
SR	Slew Rate	See ⁽²⁾	0.45	V/µs
GBW	Gain-Bandwidth Product		1	MHz
Φ _m	Phase Margin		70	Deg
G _m	Gain Margin		15	dB
e _n	Input-Referred Voltage Noise	f = 1 kHz, V _{CM} = 1V	45	nV/√Hz
in	Input-Referred Current Noise	f = 1 kHz	0.1	pA/ √ Hz
THD	Total Harmonic Distortion	$f=1 \text{ kHz, } A_V=+1 \\ R_L=600\Omega, \ V_O=1 \ V_{PP}$	0.069	%
	Amp-to-Amp Isolation	See ⁽³⁾	140	dB

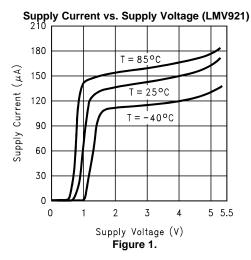
Typical Values represent the most likely parametric norm.
 V⁺ = 5V. Connected as voltage follower with 5V step input. Number specified is the slower of the positive and negative slew rates.
 Input referred, V⁺ = 5V and R_L = 100kΩ connected to 2.5V. Each amp excited in turn with 1kHz to produce V_O = 3V_{PP}.

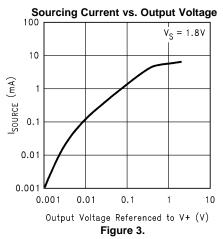


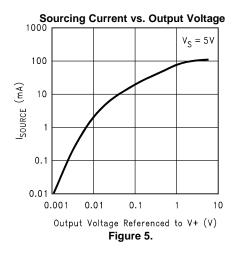
TYPICAL PERFORMANCE CHARACTERISTICS

Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.







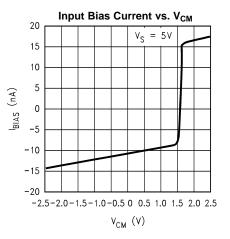
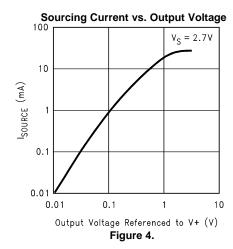
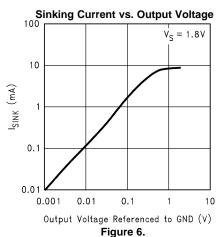


Figure 2.





INSTRUMENTS

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

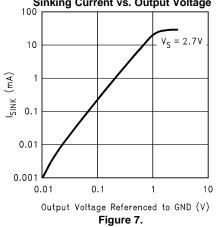
*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

Sinking Current vs. Output Voltage

100

100

100





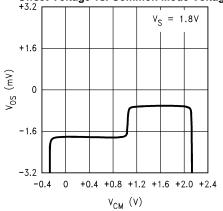
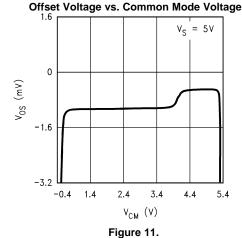


Figure 9.



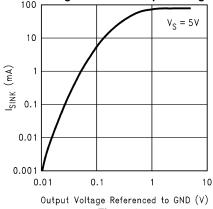
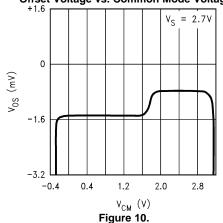


Figure 8.

Offset Voltage vs. Common Mode Voltage



Output Voltage Swing vs. Supply Voltage

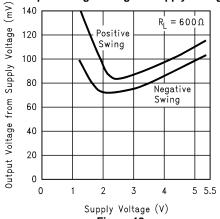


Figure 12.

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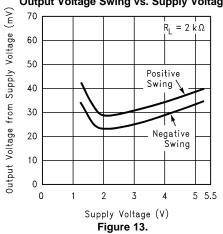


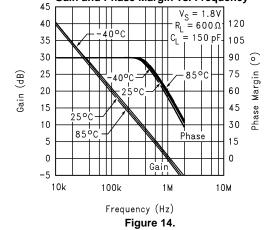
Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

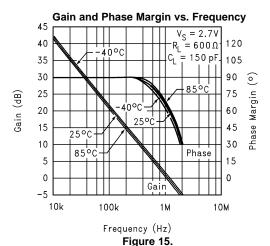
*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

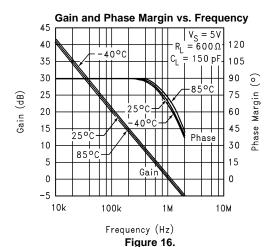
Output Voltage Swing vs. Supply Voltage

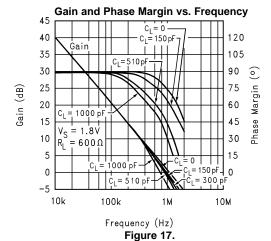
Gain and Phase Margin vs. Frequency

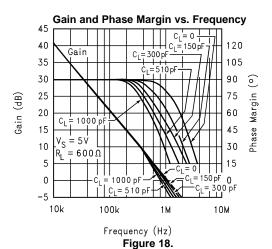








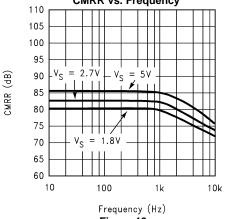




TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail. CMRR vs. Frequency





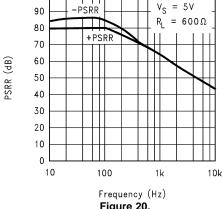


Figure 20.

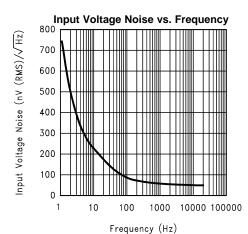


Figure 21.

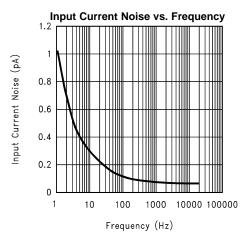
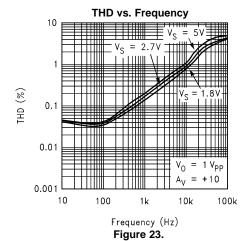


Figure 22.

THD vs. Frequency

10



THD (%) 0.1 0.01 v_0 0.001 10k 100k

Frequency (Hz)

Figure 24.



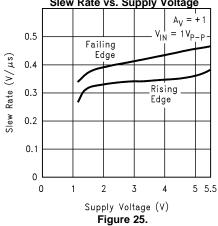
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

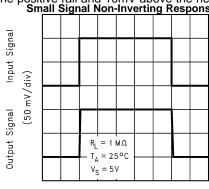
Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

Slew Rate vs. Supply Voltage

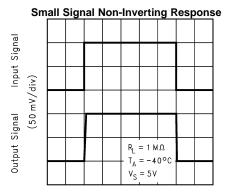
Small Signal Non-Inverting Response





Time (10 μ s/div)

Figure 26.



Time (10 μ s/div) **Figure 27.**

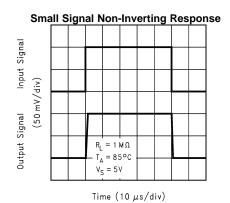


Figure 28.

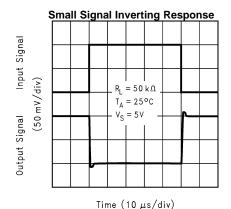
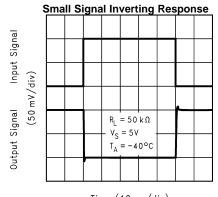


Figure 29.



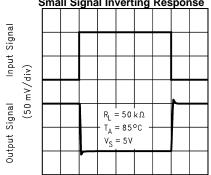
Time (10 μ s/div) **Figure 30.**

Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

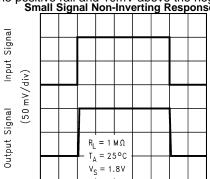
*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

Small Signal Inverting Response

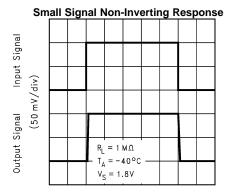
Small Signal Non-Inverting Response



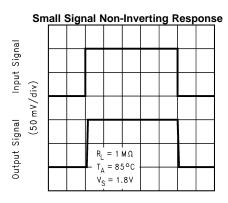
Time (10 μ s/div) **Figure 31.**



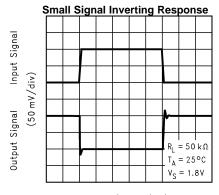
Time (10 μ s/div) **Figure 32.**



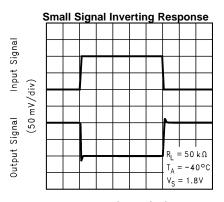
Time (10 μ s/div) **Figure 33.**



Time (10 μ s/div) **Figure 34.**



Time (10 μ s/div) **Figure 35.**



Time (10 μ s/div) **Figure 36.**

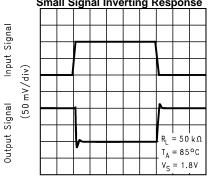


Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

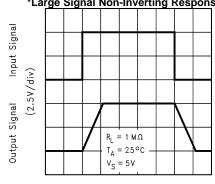
*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

Small Signal Inverting Response

Large Signal Non-Inverting Response



Time (10 μ s/div) **Figure 37.**



Time (10 μ s/div) **Figure 38.**

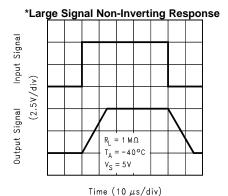
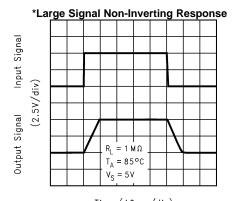


Figure 39.



Time (10 μ s/div) **Figure 40.**

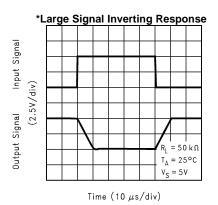
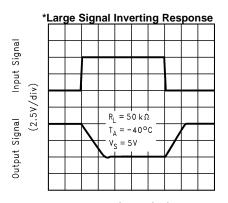


Figure 41.



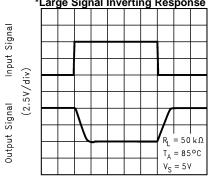
Time (10 μ s/div) **Figure 42.**

Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

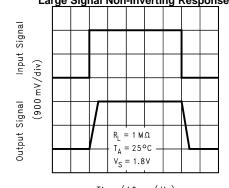
*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

Large Signal Inverting Response

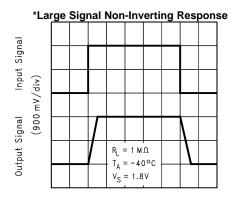
Large Signal Non-Inverting Response



Time (10 μ s/div) Figure 43.



Time (10 μ s/div) Figure 44.



Time (10 μ s/div) Figure 45.

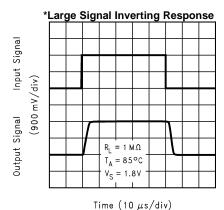
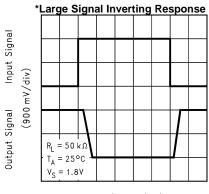


Figure 46.



Time (10 μ s/div) Figure 47.

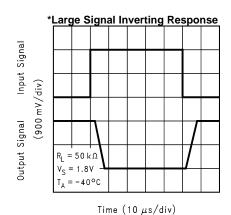


Figure 48.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25$ °C.

*For large signal pulse response in the unity gain follower configuration, the input is 5mV below the positive rail and 5mV above the negative rail at 25°C and 85°C. At -40°C, input is 10mV below the positive rail and 10mV above the negative rail.

*Large Signal Inverting Response

Short Circuit Current vs.Temperature (sinking)

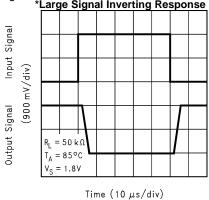


Figure 49.

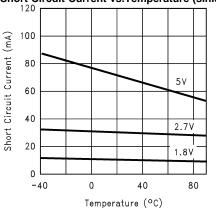
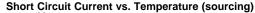


Figure 50.



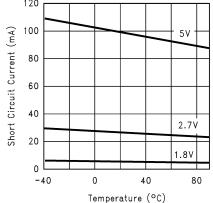


Figure 51.



APPLICATION NOTE

Unity Gain Pulse Response Considerations

The unity-gain follower is the most sensitive configuration to capacitive loading. The LMV921/LMV922/LMV924 family can directly drive 1nF in a unity-gain with minimal ringing. Direct capacitive loading reduces the phase margin of the amplifier. The combination of the amplifier's output impedance and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation. The pulse response can be improved by adding a pull up resistor as shown in Figure 52

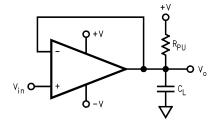


Figure 52. Using a Pull-Up Resistor at the Output for Stabilizing Capacitive Loads

Higher capacitances can be driven by decreasing the value of the pull-up resistor, but its value shouldn't be reduced beyond the sinking capability of the part. An alternate approach is to use an isolation resistor as illustrated in Figure 53.

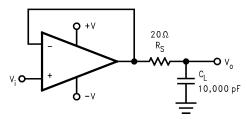


Figure 53. Using an Isolation Resistor to Drive Heavy Capacitive Loads

Input Bias Current Consideration

The LMV921/LMV922/LMV924 family has a bipolar input stage. The typical input bias current (I_B) is 12nA. The input bias current can develop a significant offset voltage. This offset is primarily due to I_B flowing through the negative feedback resistor, R_F . For example, if I_B is 50nA (max room) and R_F is 100k Ω , then an offset voltage of 5mV will develop ($V_{OS} = I_B X R_F$). Using a compensation resistor (R_C), as shown in Figure 54, cancels this affect. But the input offset current (I_{OS}) will still contribute to an offset voltage in the same manner.



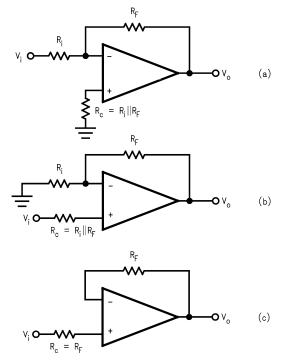


Figure 54. Canceling the Voltage Offset Effect of Input Bias Current

Operating Supply Voltage

The LMV921/LMV922/LMV924 family is ensured to operate from 1.8V to 5.0V. They will begin to function at power voltages as low as 1.2V at room temperature when unloaded. Start up voltage increases to 1.5V when the amplifier is fully loaded (600Ω to mid-supply). Below 1.2V the output voltage is not ensured to follow the input. Figure 55 below shows the output voltage vs. supply voltage with the LMV921/LMV922/LMV924 configured as a voltage follower at room temperature.

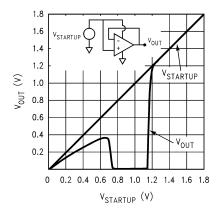


Figure 55. Output Voltage vs. Supply Voltage

Input and Output Stage

The rail-to-rail input stage of this family provides more flexibility for the designer. The LMV921/LMV922/LMV924 use a complimentary PNP and NPN input stage in which the PNP stage senses common mode voltage near V and the NPN stage senses common mode voltage near V. The transition from the PNP stage to NPN stage occurs 1V below V $^+$. Since both input stages have their own offset voltage, the offset of the amplifier becomes a function of the input common mode voltage and has a crossover point at 1V below V $^+$ as shown in the V $_{OS}$ vs. V $_{CM}$ curves.

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This V_{OS} crossover point can create problems for both DC and AC coupled signals if proper care is not taken. For large input signals that include the V_{OS} crossover point in their dynamic range, this will cause distortion in the output signal. One way to avoid such distortion is to keep the signal away from the crossover. For example, in a unity gain buffer configuration and with $V_S = 5V$, a 5V peak-to-peak signal will contain input-crossover distortion while a 3V peak-to-peak signal centered at 1.5V will not contain input-crossover distortion as it avoids the crossover point. Another way to avoid large signal distortion is to use a gain of -1 circuit which avoids any voltage excursions at the input terminals of the amplifier. In that circuit, the common mode DC voltage can be set at a level away from the V_{OS} cross-over point.

For small signals, this transition in V_{OS} shows up as a V_{CM} dependent spurious signal in series with the input signal and can effectively degrade small signal parameters such as gain and common mode rejection ratio. To resolve this problem, the small signal should be placed such that it avoids the V_{OS} crossover point.

In addition to the rail-to-rail performance, the output stage can provide enough output current to drive 600Ω loads. Because of the high current capability, care should be taken not to exceed the 150°C maximum junction temperature specification.

Power-Supply Considerations

The LMV921/LMV922/LMV924 are ideally suited for use with most battery-powered systems. The LMV921/LMV922/LMV924 operate from a single +1.8V to +5.0V supply and consumes about 145µA of supply current per Amplifier. A high power supply rejection ratio of 78dB allows the amplifier to be powered directly off a decaying battery voltage extending battery life.

Table 1 lists a variety of typical battery types. Batteries have different voltage ratings; operating voltage is the battery voltage under nominal load. End-of-Life voltage is defined as the voltage at which 100% of the usable power of the battery is consumed. Table 1 also shows the typical operating time of the LMV921.

Distortion

The two main contributors of distortion in LMV921/LMV922/LMV924 family is:

- 1. Output crossover distortion occurs as the output transitions from sourcing current to sinking current.
- 2. Input crossover distortion occurs as the input switches from NPN to PNP transistor at the input stage.

To decrease crossover distortion:

- 1. Increase the load resistance. This lowers the output crossover distortion but has no effect on the input crossover distortion.
- 2. Operate from a single supply with the output always sourcing current.
- 3. Limit the input voltage swing for large signals between ground and one volt below the positive supply.
- 4. Operate in inverting configuration to eliminate common mode induced distortion.
- 5. Avoid small input signal around the input crossover region. The discontinuity in the offset voltage will effect the gain, CMRR and PSRR.

Table 1. LMV921 Characteristics with Typical Battery Systems.

Battery Type	Operating Voltage (V)	End-of-Life Voltage (V)	Capacity AA Size (mA - h)	LMV921 Operating time (Hours)
Alkaline	1.5	0.9	1000	6802
Lithium	2.7	2.0	1000	6802
Ni - Cad	1.2	0.9	375	2551
NMH	1.2	1.0	500	3401



TYPICAL APPLICATIONS

Half-wave Rectifier with Rail-To-Ground Output Swing

Since the LMV921 input common mode range includes both positive and negative supply rails and the output can also swing to either supply, achieving half-wave rectifier functions in either direction is an easy task. All that is needed are two external resistors; there is no need for diodes or matched resistors. The half wave rectifier can have either positive or negative going outputs, depending on the way the circuit is arranged.

In Figure 56 the circuit is referenced to ground, while in Figure 57 the circuit is biased to the positive supply. These configurations implement the half wave rectifier since the LMV921 can not respond to one-half of the incoming waveform. It can not respond to one-half of the incoming because the amplifier can not swing the output beyond either rail therefore the output disengages during this half cycle. During the other half cycle, however, the amplifier achieves a half wave that can have a peak equal to the total supply voltage. R_I should be large enough not to load the LMV921.

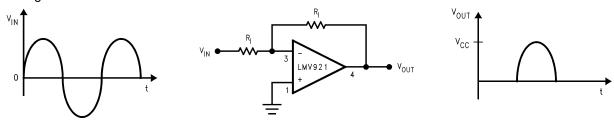


Figure 56. Half-Wave Rectifier with Rail-To-Ground Output Swing Referenced to Ground

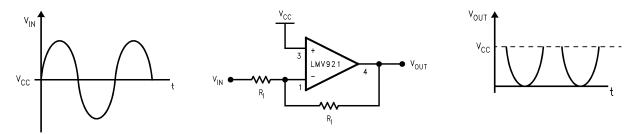


Figure 57. Half-Wave Rectifier with Negative-Going Output Referenced to V_{CC}

Instrumentation Amplifier with Rail-To-Rail Input and Output

Using three of the LMV924 Amplifiers, an instrumentation amplifier with rail-to-rail inputs and outputs can be made.

Some manufacturers use a precision voltage divider array of 5 resistors to divide the common mode voltage to get a rail-to-rail input range. The problem with this method is that it also divides the signal, so in order to get unity gain, the amplifier must be run at high loop gains. This raises the noise and drift by the internal gain factor and lowers the input impedance. Any mismatch in these precision resistors reduces the CMRR as well. Using the LMV924 eliminates all of these problems.

In this example, amplifiers A and B act as buffers to the differential stage. These buffers assure that the input impedance is very high and require no precision matched resistors in the input stage. They also assure that the difference amp is driven from a voltage source. This is necessary to maintain the CMRR set by the matching R_1 - R_2 with R_3 - R_4 .

The gain is set by the ratio of R_2/R_1 and R_3 should equal R_1 and R_4 equal R_2 .

With both rail-to-rail input and output ranges, the input and output are only limited by the supply voltages. Remember that even with rail-to-rail outputs, the output can not swing past the supplies so the combined common mode voltages plus the signal should not be greater that the supplies or limiting will occur. For additional applications, see TI application notes AN-29, AN-31, AN-71, and AN-127.

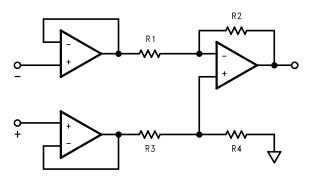
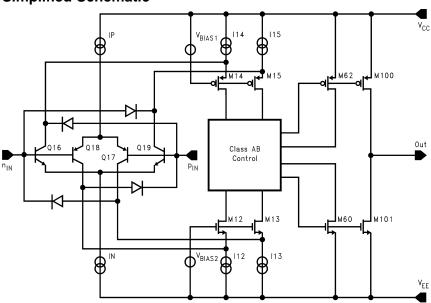
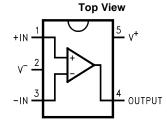


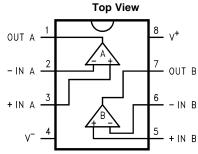
Figure 58. Rail-to-rail instrumentation amplifier

Simplified Schematic



Connection Diagrams





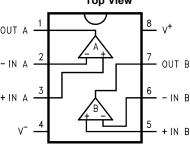


Figure 59. 5-Pin SC70-5/SOT-23-5 **Package**

Figure 60. 8-Pin VSSOP/SOIC **Package**

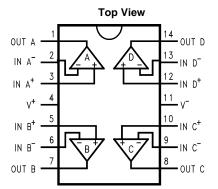


Figure 61. 14-Pin TSSOP/SOIC **Package**

LMV921, LMV922, LMV924



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REVISION HISTORY

Cł	nanges from Revision G (April 2013) to Revision H	Pa	ge
•	Changed layout of National Data Sheet to TI format		21

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